



M T B F

(E I A J R C R - 9 1 0 2)

Model	DHS50B03
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Reference
1	I C	Monolithic	2	0.0650	
2		Hybrid	0	0.0000	
3	Transistors		13	0.3080	
4	Diodes		28	0.4550	
5	LED-Optocouplers		2	0.1400	
6	Resistors		85	0.4366	
7	Capacitors		42	0.2590	
8	Transformer-Choke Coil		3	0.0460	
9	Connectors		477	0.1972	
10	Others		2	0.1130	
Total Failure Rate [10 ⁻⁶ /H]				2.0198	

M T B F	[H]	496,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—